

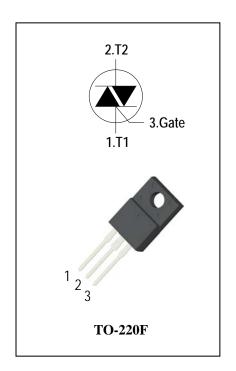
### 3 Quadrants Triacs

### **General Description**

High current density due to mesa technology .the ADT30C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners, Rectifier-fed DC inductive loads e.g.DC motors and solenoids, motor speed controllers.

### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current ( I<sub>T(RMS)</sub>= 30A )
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant



# **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Denotitive Deak Off State Voltage	Ti = 25°C	ADT30C60F	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADT30C80F	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T <sub>C</sub> = 75°C		30	Α
$I_{TSM}$	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		270/285	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		488	A <sup>2</sup> s
-11/-14	Critical rate of rise of on-state	itical rate of rise of on-state F = 120 Hz Tj = 125°C			A /
dl/dt	current	$I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$	55	A/µs	
$I_{GM}$	Peak Gate Current	tp = 20 μs Tj = 125°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			1	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			10	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
$T_{STG}$	Storage Temperature			- 40 ~ 150	°C



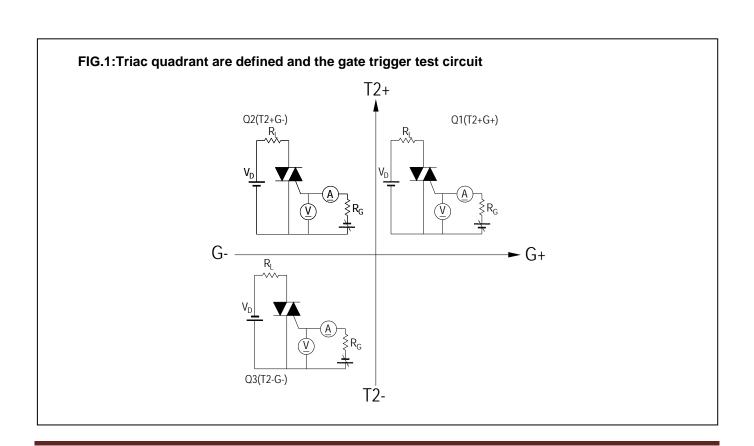


1/6 www.advsemi.com Feb,2013 -Rev.3.02



# **Electrical Characteristics**( Tj = 25°C unless otherwise specified )

Symbol	Items		Conditions		ADT30C60F/80F		30F	Unit
-					S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C	May	5		uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 125$ °C	Max.	3		mA	
V <sub>TM</sub>	Peak On-S	tate Voltage	I <sub>TM</sub> = 42A, t <sub>p</sub> = 380 μs	Max.	1.5			V
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V	
V <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 000	Max.	1.3			V
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	20	50	75	mA
	Q1-Q3	Latabia a Commant	$I_G = 1.2 I_{GT}$ Max.	May	20	80	90	m ^
lι	Q2	Latching Current		35	90	110	mA	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	500	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		(dl/dt)c=-12A/ms Tj = 125°C	Min.	1	15	20	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)		Max.	1.7		°C/W		
R <sub>th(j-a)</sub>	Junction to ambient		Max.	60		°C/W		



# **ADV**

FIG.2: Maximum on-state power dissipation

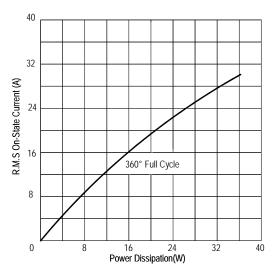


FIG.4: Maximum transient thermal impedance

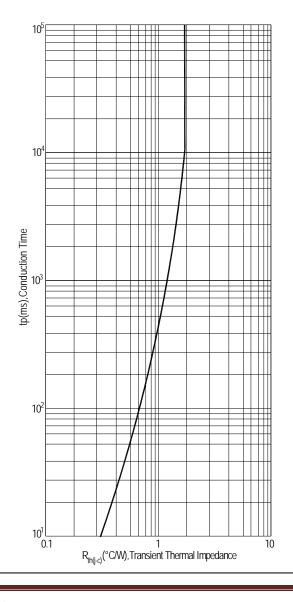


FIG.3: Typical RMS on-state current VS Allowable case Temperature

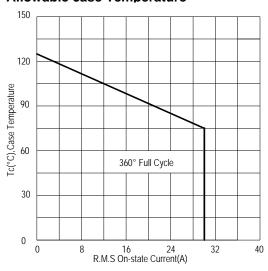


FIG.5: Rated surge on-state current (Non-Repetitive)

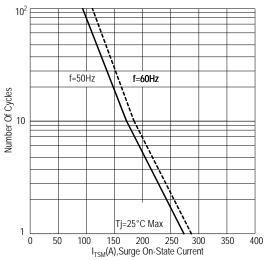


FIG.6: Gate trigger current VS Junction temperature

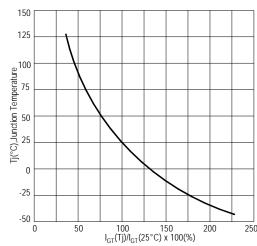






FIG.7:Holding current and Latching current VS Junction temperature

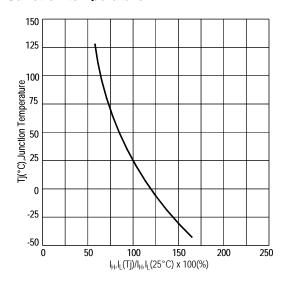


FIG.8: Gate trigger voltage VS Junction temperature

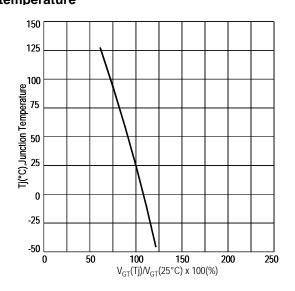
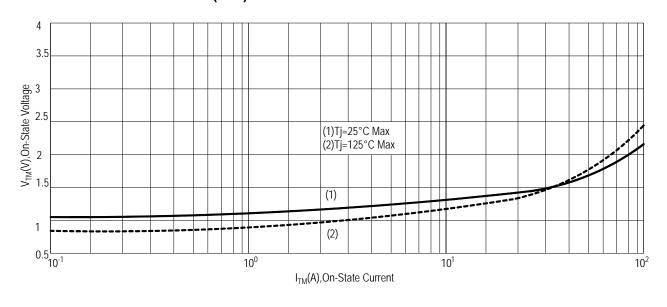


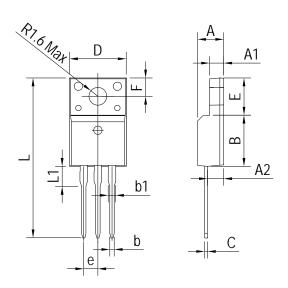
FIG.9: On-state characteristics(Max)



4 / 6 www.advsemi.com Feb,2013 -Rev.3.02

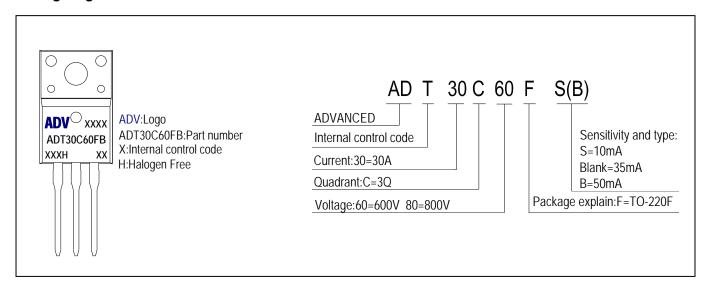


# PACKAGE MECHANICAL DATA TO-220F Package Dimension



	Dimens	sions In	Dimensions In			
Symbol	Millimeters		Inches			
	Min	Max	Min	Max		
Α	4.300	4.800	0.169	0.189		
A1	2.400	2.700	0.094	0.106		
A2	2.500	3.000	0.098	0.118		
В	8.800	9.300	0.346	0.367		
b	0.600	0.950	0.023	0.037		
b1	1.100	1.700	0.043	0.067		
С	0.500	0.750	0.020	0.030		
D	9.700	10.360	0.382	0.408		
Е	6.400	6.800	0.252	0.268		
е	2.540 TYP		0.100 TYP			
F	3.300 REF		0.130 REF			
L	28.000 30.000		1.102	1.181		
L1	2.900	3.630	0.114	0.143		

### **Making Diagram**



### **Ordering information**

Part number	Package	Marking	Packing	Quantity		
ADT30C60F#	TO-220F	ADT30C60F#	Tube	50pcs		
ADT30C80F#	TO-220F	ADT30C80F#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



# ADT30C60F/80F

#### Notice

- 1. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any ADV products listed in this document, please confirm the latest product information with a ADV sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by ADV such as that disclosed through our website. (http://www.advsemi.com )
- 2. ADV has used reasonable care in compiling the information included in this document, but ADV assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document.
- 3. You should use the products described herein within the range specified by ADV, especially with respective the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. ADV shall have no liability for malfunctions or damages arising out of the use of ADV products beyond such specified ranges.
- 4. When using or otherwise relying on the information in this document, you should evaluate the information in light of the total system before deciding about the applicability of such information to the intended application. ADV makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or ADV products.
- 5. Although ADV endeavors to improve the quality and reliability of its products, IC products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a ADV product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by
- 6. This document is provided for reference purposes only so that ADV customers may select the appropriate ADV products for their use. ADV neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of ADV or any third party with respect to the information in this document.
- 7. ADV shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.
- 8. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written approval from ADV.

6 / 6 www.advsemi.com Feb,2013 -Rev.3.02